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The subsurface diffusion of hydrogen on rutile TiO₂ surfaces: A periodic DFT study

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Abstract

Titanium oxide (TiO₂) is an oxide with a wide range of technological and industrial applications. The interaction of hydrogen with TiO₂ surface is an important step in many catalytic processes, such as spillover or water photosplitting. In the last years, the role of the subsurface hydrogen has been invoked many times to explain different phenomena, from black titania to reversible storage. In this work, we systematically investigate the paths for hydrogen diffusion from surface into subsurface focusing on the surface topology, the thermal and isotopic effects, and the degree of reduction of the substrate, by means of state of the art periodic DFT calculations. We find differences in the behavior of the rutile ${\rm TiO}_2$ surfaces (001), (100) and (110) slightly exothermic reaction energies from -0.02 eV to -0.15 eV, and activation energies from 0.39 eV to 1.00 eV. Deuterium diffusion from rutile (110) surface to the bulk, as well as thermal effects, were found to affect less than 0.04 eV the energy profile. On the contrary, the degree of reduction of the rutile (110) was found to noticeably decrease the activation barrier down to 0.8 eV for the (110) slab. We analyze structural, electronic and reactivity parameters that affect the kinetic barriers for the surface to subsurface H diffusion, and conclude that topology and reduction degree are valid strategies to tune the surface-tobulk migration process.

Keywords: hydrogen diffusion, topology effect, rutile TiO₂, isotopic effect, thermal correction

1 Introduction

TiO₂ has been widely studied as a model metal oxide with a large number of applications, such as solar cells [1, 2], sensors [3, 4], photocatalysts [5] or heterogeneous catalysts [6]. The interaction of hydrogen with TiO₂ surfaces is an important step in many reaction processes, such as hydrogen storage, hydrogen spillover or photocatalytic water splitting to cite a few. In the last years many studies have pointed out the importance of subsurface hydrogen, which could be determining for many observations such as the reversible absorption in anatase nanoparticles [7], the stabilization of surface hydrogen intermediates [8], the properties of black titania [9], its role in hydrogen permeable membranes [10], or the infrared baseline of titania-based catalysts [11]. In the present work we investigate the mechanisms for subsurface diffusion in rutile substrates, focusing on the role of the topology, the degree of reduction and the isotopic effect, by means of state of the art theoretical tools based on density functional theory (DFT).

Frequently, adsorbed hydrogen is observed on TiO₂ surfaces due to the standard surface science cleaning procedures [12], or is achieved by direct adsorption of atomic atoms on single crystals [13], and photolysis of adsorbed carboxylic acids [14]. The activity of the TiO₂ is highly affected by extrinsic (hydrogen impurity) defects, which supply a charge excess. As a consequence, the electronic properties as well as the bandgap of TiO₂ can be influenced [15, 16]. Moreover, many reports have shown that the hydrogenation of TiO₂ can boost the photo-absorption of TiO₂ and its photocatalytic activity for the splitting of water to H₂ [17–22]. Numerous experimental and theoretical works have been carried out to study the H-TiO₂ system [10, 12, 23–28]. It was widely proved that atomic H instead of molecular H₂ can react with TiO₂ surface. Still, a clear picture of the physico-chemical features affecting H migration to the subsurface is still missing.

In 2008, some of us reported for the first time indirect evidence for the stabilization of bulk hydrogen in a TiO₂ single-crystal [13], which were consistent with the experimental observations: heating of the hydrogenated sample removes surface hydrogen but does not lead to recombinative desorption of H_2 (or H_2O) molecules, with a barrier of 1.11 eV. The presence of stable subsurface hydrogen was confirmed experimentally by an

independent group one year later [29]. Subsurface hydrogen atoms are found to reside in a stable interstitial site as subsurface OH groups detectable in scanning tunneling microscopy. Some years later we predicted that the migration to the bulk could also occur in anatase TiO_2 (101), requiring barriers varying from 0.70 to 2.25 eV, depending on the diffusion path [26].

Selloni et al. reported the reversible incorporation into cubic and octahedral TiO_2 anatase nanocrystals [7], and later provided valuable experimental and theoretical information on different coverages and pathways, possible adsorption sites, and the presence of defects for H diffusion on anatase (101) [25]. Recently, a combined theoretical and experimental study confirmed the subsurface diffusion of H atom in anatase TiO_2 by observing a hydrogenated surface shell, which is formed through subsurface diffusion of photo-reduced water protons generated at the aqueous TiO_2 interface. An overall theoretical barrier for the preferred pathway of 0.77 eV [30] was determined.

The diffusion of H in TiO₂ including anatase and rutile TiO₂ has been studied by various experimental methods [31, 32]. Ohashi et al. investigated the hydrogenation of rutile TiO₂ (110) surface by low-energy hydrogen ions, by means of ultraviolet photoemission spectroscopy (UPS), X-ray photoemission spectroscopy (XPS) and nuclear reaction analysis (NRA) [31]. It was found that H atoms are distributed to a depth of 30nm with an average concentration of 5.6 at.%. Subsurface sites were confirmed to be stable sites for hydrogen. Moreover, N. Nagatsuka et al. carried out similar experiment, but for anatase (101) at different temperature (200K and 300K) [32]. Their results showed that H diffusion in anatase TiO₂ is much faster than in rutile TiO₂.

It is well known that the surface properties strongly vary with different crystallographic orientations, which can greatly affect their reactivity [33, 34]. While previous studies mainly focus on one surface, there is no systematic investigation with various orientations for H diffusion on TiO_2 . In this work we address the role of the termination in the diffusion mechanisms of hydrogen for three terminations of rutile TiO_2 . We furthermore analyze how geometry and electronic structure affect the migration energetic profile.

Other phenomena could also modify the diffusion of hydrogen to the

lattice. For instance, quantum tunneling due to the light weight of hydrogen could facilitate migration [35]. Thermal effects may also increase the migration rate. Besides, the presence of excess electrons due to the easy reduction of Ti⁴⁺ to Ti³⁺ might also have an impact in the reaction barriers, as shown recently for water adsorption/desorption processes [36]. In order to address these effects, we include in the present work isotopic substitution by deuterium, thermal corrections and substrate degree of reduction for the (110) termination. We discuss the results and suggest that the morphology of the surface and the degree of reduction of the substrate should play key roles in the control of H surface to bulk migration phenomena.

2 Computational methods

Periodic DFT calculations have been performed in the generalized gradient approximation and the Perdew-Berke Ernzerhof functional PBE [37] as implemented in the Vienna ab initio simulation package (VASP) [38, 39] 5.4.4 version. Projector Augmented Wave (PAW) pseudopotentials were applied to describe the core electron representation, with 1, 4 and 6 valence electrons for H, Ti and O respectively [38, 39]. The GGA+U approach of Dudarev et al was used to treat the 3d electrons of Ti with the effective Hubbard on-site Coulomb interaction parameter (U' = U J) [40]. We choose U' = 4 according to the proposed value from previous works [26, 41]. A 400 eV cutoff energy for the plane-wave basis set was found to be sufficient in the case of rutile surface [13]. The energies were converged to 10^{-4} eV for the electronic loop, and the forces acting on each atom were smaller than 0.03 eV/Å.

The adsorption energy, or binding energy (E_b) of the hydrogen on oxygen sites is calculated according to the equation below:

$$E_{b} = E_{slab/H} - E_{slab} - \frac{1}{2}E_{H_{2}}$$
(1)

where E_{slab} and $E_{slab/H}$ indicate the energies of the bare slab and with hydrogen adsorbed on the slab, respectively, and E_{H_2} is the energy of a hydrogen molecule in a box (-6.76 eV).

In this study, (001), (100), and (110) terminations of rutile TiO₂

were investigated. The size, composition, coordination number of surface sites for three slab models are shown in Fig. 1 and Table 1. These three stoichiometric facets were modeled as a two-dimensional slab in a three-dimensional periodic cell. The slabs were cleaved from relaxed rutile TiO₂ bulk unit cell. For the part of hydrogen migration in bulk, a 2x2x2 bulk supercell is used for comparison with slabs. All our slabs consist of eight TiO₂ units, and were built with the MAPS software [42], with eight TiO₂ layers in thickness for (001), (100) and four TiO₂ layers for (110). A vacuum thickness of 20 Å was introduced to prevent interaction between slabs. The bottom-half layers of the slab models were kept frozen and the upper-half layers were allowed to relax.

As regards the coverage, a range of values is reported in the literature for (110): 0.25 ML is found in ref. [43], 0.66 ML is found after exposure to high amounts of H in ref. [13], and 1 ML (1 x 1 pattern) is characterized in ref. [44]. Based on the latter, we have chosen to model high coverage for all the terminations considered. In order to analyze the effect of the coverage, we have computed the adsorption energy in bigger unit cells (See SI Table S 1) and the results are discussed below.

The CI-NEB methods (constrained minimization and climbingimage nudged elastic band methods) were used for searching TS (transition states) [45]: the minimum energy pathway for each elementary reaction was discretized by a total of 4 images between the initial and final states. Then the Improved Dimer Method (IDIM) was applied to find the stationary point [46]. All the transition states were identified by performing the frequency analysis. Only one imaginary frequency was obtained and was checked to connect to the initial and final states. The structures for initial, TS and final systems for the three slabs can be found in the supporting information. The zero point energy (ZPE) was computed as one-half of the sum of real vibration frequencies, to correct adsorption energies.

Table 1 Size, composition, layers, coordination numbers for three rutile TiO_2 surfaces.

	(001)	(100)	(101)
Supercell	1x1	1x1	1x1
Composition (TiO ₂ units)	8	8	8
TiO ₂ layers (frozen/relaxed)	4/4	4/4	2/2
Atoms (frozen/relaxed)	12/12	12/12	12/12
Coordination	Ti(4),O(2,3)	Ti(5),O(2,3)	Ti(5,6),O(2,3)
Parameter (a.b)(Å)	a=b=4.661	a=4.661,b=2.962	a=2.962,b=6.592

The Gibbs free energy at room temperature (298K) was also considered within the following approximations:

$$G(T) = H - TS = U + pV - TS \approx U(T) - TS(T)$$
⁽²⁾

For the adsorption system, it is reasonable to consider only the vibrational contributions:

$$U(T) = E_{DFT} + E_{ZPE} + U_{vib}(T)$$
⁽³⁾

$$S(T) = S_{vib}(T) \tag{4}$$

$$U_{vib}(T) = \sum_{i=1}^{3N-6} \left(\frac{hv_i}{e^{-\frac{hv_i}{K_B T} - 1}} \right)$$
(5)

$$S_{vib}(T) = K_B \sum_{i=1}^{3N-6} \left(\frac{hv_i}{K_B T}\right) - \ln(1 - \frac{hv_i}{K_B T})$$
(6)

$$G(T) \approx F(T) = E_{DFT} + E_{ZPE} + K_B T \sum_{i=1}^{3N-6} \left[\ln(1 - e^{-\frac{hv_i}{K_B T}}) \right]$$
(7)

where G is the Gibbs free energy of the system for temperature T and pressure P, S is entropy, H is enthalpy and U is internal energy.



Fig. 1 Side views of rutile TiO₂ (001) (a), (100)(b), (110) (c) surfaces. Ti, blue; O, red.

3 Results and discussion

3.1 Adsorption of H on rutile TiO₂ surfaces (001), (100), (110)

The adsorption of one H was studied by placing the H atom at different sites of surface and subsurface for rutile (001), (100) and (110) surface in a 1 x 1 unit cell. The oxygen sites considered are labeled as O_{2C} , O_{3C} and O_{sub} . The calculated adsorption energy is shown in Table 2, and compared with the previous literature. The topology of each surface imposes the adsorption modes. The (110) two-fold coordinated sites is the most stable one with -0.30 eV, and the corresponding subsurface position is slightly destabilized, with adsorption energy of 0.18 eV. The trend is similar to that found in ref. [13], and is preserved if no U parameter is considered. The (001) termination stabilizes subsurface positions by -0.05 eV and the (100) surface by 0.06 eV.

Table 2 Calculated adsorption energies, $E_b(eV),\, for\, H$ adsorption on the rutile TiO_2 (001), (100) and (110) surface.

Types	(001)	(100)	(110)
••	DFT+U	DFT+U	DFT+U/Ref[13]
1 H: O _{2C}	0.43		-0.30/-0.23
1 H: O _{3C}	-0.03	0.14	0.33/0.44
1 H: O _{sub}	-0.05	0.06	0.18/0.40

3.2 Diffusion of hydrogen on rutile TiO₂ surfaces (001),

(100), (110)

The pathways and structures for hydrogen diffusion from surface to subsurface are reported in Table 3 and Fig. 2, where the starting, transition state, and final structures are shown together with the energy profile. The path for hydrogen diffusion on rutile (001) is shown in Fig. 2 (a). In the starting structures, the H is attached to O_{3C} with an O-H of 1.00 Å. In the transition state, one H migrates from O_{3C} to O_{sub} . In the final structure, one H is bound to Osub. The energy difference (ΔE) between the final and initial species of this migration process is -0.02 eV. The activation barrier (Eact) is 0.39 eV, indicating possibly reversible migration. There is another pathway for H diffusion, that is from O_{2C} to O_{sub} . However, the H_{Osub} is found to be less stable than the H_{O2C} , by 0.48 eV. The distance between these two atoms is long, 2.816 Å, and the OH needs to rotate in this case, making this pathway unlikely. So we consider the H diffusion from O_{3C} to O_{sub} .

The adsorption energies with bigger unit cells were also calculated, and are shown in Table S1. The results indicate that with bigger unit cells (2x2) and lower coverage (0.25 ML), the hydrogen adsorption is stronger than higher coverage (1 ML), but the adsorption trend among (001), (100) and (110) is maintained. For the H diffusion on (100) (Fig. 2 (b)), one H is bound to O_{3C} of the surface, then migrates to the subsurface region to form a bond with the O_{sub} . In this process, the calculated ΔE is -0.08 eV, and the activation barrier of H migration is 0.79 eV, indicating that H diffusion to the subsurface region is an activated process, thermodynamically slightly favorable. For (110) it was shown previously that the direct



Fig. 2 Schematic structures of TS as well as energy profile in the diffusion process on three rutile TiO₂ facets are shown. E_{act} indicates the activation barrier. ΔE is the reaction energy. (a), (b) and (c) are for (001), (100) and (110) respectively.

migration O_{2C} to subsurface was more energetic [47]. Fig. 2(c) displays the diffusion of H from O_{3C} to the subsurface site. In this process, the final structure is more stable than the initial one with an energy difference of -0.15 eV. However, the higher barrier (1.00 eV) makes this process less likely to occur compared to other terminations. The value of 1.00 eV is consistent with the previous reports (1.11 eV [13], 0.93 eV [47]). The small difference can come from the different coverage, layers and sizes, and the use of GGA+U in the present work.

We also calculated the energy profile without U correction (values in brackets of Table 3). The trend is the same as that when U correction was applied. The activation barriers are higher without U correction, while the thermodynamic energies change very slightly.

Table 3 Energy profile for the hydrogen diffusion process on three rutile facets. ΔE is the reaction energy. E_{act} indicates the activation barrier. Values in brackets are without U correction.

	(001)	(100)	(110)
Initial state	0.00(0.00)	0.00(0.00)	0.00(0.00)
Eact	0.39(0.43)	0.71(0.79)	1.00(1.03)
ΔΕ	-0.02(-0.03)	-0.08(-0.09)	-0.15(-0.19)

3.3 H diffusion in the bulk TiO₂

Once in the subsurface, H binds to a lattice O forming a hydroxyl group, that can migrate inside the structure. We have considered three diffusion paths of the H atom in the bulk (See Fig. 3). These diffusion paths are described in detail below and the activation barriers are indicated in Table 4. The H in the bulk is thus bound to O_{3C} , with a distance 0.998 Å for the O-H bond. Three migration paths, involving other O_{3C} sites, are considered, with an energy difference (ΔE) of zero. The H diffuses through a small cavity with activation barrier ranging from 0.32 eV to 0.97 eV. The first path involves the migration from one cavity to a neighboring cavity, see Fig. 3(b), and the activation energy is 0.97 eV. The most likely migration pathway is the migration of H from O_b to O_d (see Fig. 3(c)), with the lowest energy barrier, only 0.32 eV. The two O atoms involved in this process are positioned directly opposite to each other within the same cavity, forming an H-bond, which favors H migration. For the H diffusion from O_d to O_c , the barrier is 0.53 eV, Fig. 3 (d). It involves in the same cavity between two O sites without H-bond.

Table 4 Activation Barriers E_{act} (eV), for Atomic Hydrogen diffusion in the TiO₂ bulk, see Fig. 3.

Diffusion type	E _{act}	
Path 1: $O_a \rightarrow O_b$	0.97	
Path 2: $O_b \rightarrow O_d$	0.32	
Path 3: $O_d \rightarrow O_c$	0.53	



Fig. 3 (a) A cavity of the rutile TiO₂ bulk (a $2 \times 2 \times 2$ supercell was used). (b) Path 1: H migrates in the bulk from O_a to O_b; (c) Path 2: H migrates in the bulk from O_b to O_d; (d)Path 3: H migrates in the bulk from O_d to O_c. Grey, red represent the titanium and oxygen atoms respectively.

Some of us have studied the H insertion into rutile in deeper subsurface layers (110) [13], with the energy barriers of 1.02-1.13 eV, which is consistent with the present value of 0.97 eV for the migration between neighboring cavities.

3.4 Electronic Structure

When an H adsorbs on an oxygen site, there is always a charge transfer of one electron with formation of a proton H⁺ bound to an O, and one electron that is transferred to the empty Ti 3d states, as found experimentally [48] and theoretically [41].

This can be visualized by the density of states (DOS). Thus we studied the partial DOS Ti states for the hydrogen adsorption on the oxygen site of the surface (O_{sur}) and also subsurface O_{sub} (See Fig. 4, Fig. S1-S3). Compared with the bare slab, it is clearly indicated that there is a new Ti³⁺ peak near the Fermi energy for hydrogenated slabs. This electronic feature is found for the three model slabs

used, and also for the bulk system (Fig. S3).



Fig. 4 PDOS of Ti 3d and 3p states obtained at the GGA+U level for slab (110) and hydrogenated species (H_{sur} and H_{sub}) in the diffusion process. The localized Ti³⁺ 3d¹ state is marked by an arrow. PDOS of Ti 3d and 3p states for (100), (001) and bulk are provided in SI (Fig. S1-S3).

An analysis of the spin density of the hydrogenated species has been performed (see Fig. 5, Fig. S4 and S5), which shows the location of unpaired electrons. The Bader spin analysis is reported (Table 5, Table S3, S4). One Ti was reduced for every facet. For (110), for initial state and TS, the five-fold Ti

on the surface was reduced, with around 0.97-0.99 lel. However, when H binds to the subsurface O, the subsurface Ti was mainly reduced, with 0.60 lel (Table 5 and Fig. 5), which is also found in the diffusion process of (001) (Table S1 and Fig. S4). For (100), the subsurface Ti was always reduced dur- ing the process with the integrated spin density varying from 0.84 to 0.98 lel (Table S2 and Fig.S5). One Ti was also reduced when H bound with O in the bulk, with 0.92 lel (Table S2).

Table 5 Bader charges in lel of selected Ti, O and H atoms for the hydrogen diffusion from surface to subsurface process on rutile TiO_2 (110). Inside the brackets indicates the integrated Bader spin.

	(110)			
atoms	slab	Hsur	TS	Hsub
Ti5C-sur	2.02(0.00)	1.79(0.99)	1.81(0.97)	1.98(0.25)
Ti _{sub}	2.04(0.00)	2.04(0.01)	2.06(0.02)	1.92(0.60)
0	-1.05(0.00)	-1.10(0.00)	-1.11(0.00)	-1.22(0.00)
0	-1.05(0.00)	-1.26(0.00)	-1.25(0.00)	-1.08(0.00)
Н		0.65(0.00)	0.62(0.00)	0.62(0.00)

There is a debate regarding the location of reduced Ti³⁺. The previous studies like [41] and also [49], show that it can be influenced by the computational settings such as functional, and Hubbard correction U. Moreover, the chemical environment of the OH group might also affect the position of the reduced Ti, e.g. in reference [49], the hydrogen is bound to bridging oxygen (O_{2C}), while in our process, the hydrogen is bound to three-coordinated oxygen (O_{3C}). In the present work we have chosen to focus on the energetics of the diffusion process rather than on the electron localization problem.

In addition, although in the paper [49], the most stable site for the location of excess electron occurs in the second layer directly beneath the Ti_{5C} row, there is still possibilities for the location at the surface Ti (0.1 eV less stable) and third layer (0.2 eV less stable). The energy differences (0.1 eV -0.2 eV) are not big. We have unsuccessfully tried to locate the electron in the subsurface position, and it always converges to the surface position. Assuming that the energetic effect is constant, the trends of the diffusion barriers should not be affected by the site where the excess electrons are

localized.



surface, which indicates the distribution of unpaired electrons (isosurface level=0.01). Data for (001) and (100) and bulk are provided in SI (Fig. S4 and S5).

3.5 Analysis of reactivity

Based on our results in Table 6 and Fig. 2, it is clearly seen that the diffusion of H on three surfaces behaves significantly different. We found that the activation barrier is linearly related to the distance between the O of the surface and subsurface O_{sub} in the bare slabs (Fig. 6). Moreover, when we analyze the structures of the transition states (TS in Fig. 2), it was found that for (100) and (110), the O-H needs to rotate in order to be bound to O_{sub} . For (001), the H can diffuse from O_{3C} to O_{sub} directly. Thus in these former two processes, it needs higher activation barrier than (001). The same trend is observed in the absence of U parameter, although with a worse linear correlation.



Fig. 6 The activation barrier (E_{act}) as a function of the distance between the O of the

surface and subsurface of the bare slabs.

Table 6 The activation barrier E_{act} (eV) as a function of the distance difference d(O-Osub) (Å) between the O of the surface and subsurface of the bare slab with and without U correction.

	$d-(O-O_{sub})$ (Å)	Activation barrier $(E_{act})(eV)$
Slabs		
(001)-(U=4.0 eV)	2.784	0.39
(001)-(U=0.0 eV)	2.797	0.43
(100)-(U=4.0 eV)	2.869	0.71
(100)-(U=0.0 eV)	2.827	0.79
(101)-(U=4.0 eV)	2.930	1.00
(101)-(U=0.0 eV)	2.927	1.03

3.6 Isotopic substitution and thermal corrections

In order to estimate the probability of tunneling effects we have considered the isotopic substitution of H by Deuterium for the (110) termination. The initial, transition and final structures were reoptimized. We investigated two pathways (Fig. 7, (a-b) and (c-d)) to make a comparison. For process (a-b) there is only one H in the cell that diffuses from O_{3C} to O_{sub} . For process (c-d), one additional H is present on the O_{2C} site, and H migrates from O_{3C} to O_{sub} . The results show that the energy differences between initial and final structures are slightly affected by the deuteration, (Fig. 7, (b) and (e)), decreasing by -0.09 eV, whereas the energetic barriers are increased by 0.08 eV, as expected from the higher weight of D compared to H. The two paths are also very similar as regards reaction and activation energies, despite the fact the the latter possesses a higher degree of reduction due to the presence of a second H atom. No significant isotopic substitution effect was found.

The ZPE correction was also calculated. The results (in Fig. 7, red lines) showed that there is no effect on reaction energy (ΔE), but the kinetic barrier is slightly reduced, by -0.04 to -0.02 eV. The same behavior is observed for the other two surfaces, the details for (100) and (101) are provided in SI (Fig. S6-S8).

3.7 Substrate reduction effect

The degree of reduction of the titania substrate has been studied by two sets of models schematized in Fig. 8. By adding or removing neutral species, such as water adsorption (no excess electron), H addition (each H adds one

excess electron) and O removal (each O vacancy adds 2 excess electrons) [50].



Fig. 7 Comparison of calculated reaction energies(ΔE) and activation barriers Eact for hydrogen and deuterium adsorption on the rutile (110) surfaces. In pathway (a) and (b), one H is present whereas in pathway (c) and (d) a second H is located on O_{2C}. Zero Point Energy corrected profile (red line) and uncorrected (black line) are represented.

In this case we may expect additional interactions (local relaxations, Hbonds...). Second, by modifying manually the number of electrons of the supercell, resulting in charged systems (VASP compensates the charge by a uniform background compensating charge). The transition states are just single points to keep the geometry and vacuum fixed, as they influence the energy of charged periodic systems, and the results have to be interpreted as rough trends rather than quantitative data. Thus, the resulting systems studied are:

a) neutral species

a1) the non-reduced surface (denoted as 0e) by adsorbing 1 OH⁻ and 1
H⁺, corresponds to formal water adsorption with no electron transfer
a2) the reduced surface (denoted 1 e) by adsorbing 1 H

a3) the reduced surface (denoted 2 e) by adsorbing 2 Ha4) the reduced surface (denoted 3 e) by adsorbing 1 H and removing 1O.

b) charged systems: we add 0 e, 1 e, 2 e, 3 e electrons to the slab model.

The activation barriers of diffusion in case a are 1.18 eV (neutral), 1.01 eV (1 e), 1.08 eV (2 e), 0.76 eV (3 e) respectively. The activation barriers of diffusion in case b are 1.37 eV (neutral), 1.01 eV (1 e), 0.81 eV (2 e), 0.75 eV (3 e) respectively. In both cases, the activation barrier of the diffusion on the surface with 0 e is the highest, while with 3 e is the lowest. There seems to be a trend relating high reduction state and low diffusion barrier. In realistic conditions where titania is partially reduced (presence of H impurities, oxygen vacancies), it is thus expected that migration of hydrogen to bulk positions is favored compared to stoichiometric compositions.

In order to gain more understanding in the reason behind such behavior, we perform a spin density analysis (Fig. S9) for the 8 transition states calculated. For the non-reduced surface (denoted as 0e), there is no unpaired electrons. For other kinds of reduced surface (denoted as 1e, 2e, 3e), the number of Ti sites bearing electrons increase with the reduction degree. Thus, one excess electron results mainly in the population of the Ti_{5C} site with a small contribution from a subsurface Ti, irrespective of the way it has been added. For more than one excess electrons, case a) results in a wider distribution of the spin over more Ti sites than case b). In all the situations both surface and subsurface Ti sites are involved. The reduction of subsurface Ti sites was already invoked by Jupille et al [51].



Fig. 8 The activation barriers on four kinds of reduced surfaces for hydrogen diffusion from surface to subsurface. The surfaces were reduced by two ways. (a): Adsorption of H or removing oxygen: Adsorption of 1 H⁺ and 1 OH⁻ (denoted as 0 e); Adsorption of 1 H (denoted as 1 e); Adsorption of 2 H (denoted as 2 e); Adsorption of 1 H and removing 1 O (denoted as 3 e); (b) Adding electrons to the system directly (by setting INCAR in VASP). The non-reduced surface (denoted as 0e); The reduced surface (denoted 1 e); The reduced surface (denoted 2e); The reduced surface (denoted 3e).

Based on Bader charge analysis results (Table S4), we find that Ti and H lose electrons, and O gain electrons. Interestingly, when the surfaces are more reduced, the numbers of electrons lost by Ti_a and Ti_b are fewer. That means more electrons are located in Ti_a and Ti_b when surfaces are more reduced. So Ti_a and Ti_b can attract H, the transition states are stabilized. In addition, we also find correlation between the energy barriers and the distances between Ti_b and H (See Fig. S9 (c)), and also the correction between d and reduction of the surface (See Fig. S9 (d)). The presence of excess electrons in Ti sites seems to i) decrease the electrostatic repulsion between Ti and H and ii) increase the distance between Ti_{5C} and H in the TS, both resulting in a decrease of the TS

energy and thus the barrier for migration.

4 Conclusion

The mechanisms for diffusion from surface into the subsurface over three rutile TiO₂ surfaces and bulk are investigated with PBE+U calculations. The topology structures have strong effects on kinetic barriers, while slightly change the themodynamic energies. The activation barriers of diffusion are 0.39 eV, 0.79 eV, 1.00 eV for surface (001) (100) and (110) respectively. Our results indicate that (001) shows the most favorable path for (reversible) diffusion. Once in the bulk, H could diffuse easily inside cavities with barriers as low as 0.32 eV eV, whereas migration to other cavities is more costly, 0.96 eV. We observe a linear correlation between the activation energy and the distance O_{surf} - O_{sub} in the bare slab.

For rutile (110), isotopic substitution by deuterium results in slight changes in the kinetic barriers of +0.04 eV compared to hydrogen. The presence of other surface H atom in O_{2C} position resulted in a slight increase of the activation barrier (1.08 eV vs 1.00 eV) and more negative reaction energy (-0.24 eV vs -0.15 eV). Thermal effects also affected slightly the energetic profiles.

We found that the substrate reduction degree has a moderate impact in the activation barriers, decreasing from more than 1 eV down to 0.8 eV. The reason could be the increase of the Ti-H distance in the TS that results in a stabilization and thus a decrease in the activation energy.

In summary, our results clearly indicate the complexity of the surface to subsurface hydrogen diffusion process, and suggest that controlling the topology and the reduction degree are valid strategies to tune such process.

5 Declaration of Competing Interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

6 CRediT authorship contribution statement

Baohuan Wei: Investigation, writing—original draft, and editing; Monica Calatayud: software, supervision, writing—review and editing

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